NSN 5961-00-468-3110

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View Online at https://aerobasegroup.com/nsn/5961-00-468-3110

Inclosure Material:

Metal

Overall Length:

0.468 inches

Overall Diameter:

0.380 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.438 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

5.00 amperes source cutoff current

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Thread Series Designator:

Unf

Terminal Type And Quantity:

4 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

